

TC74AC138P/F/FN

3-TO-8 LINE DECODER

The TC74AC138 is an advanced high speed CMOS 3-to-8 DECODER fabricated with silicon gate and double-layer metal wiring CMOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

When the device is enabled, 3 Binary Select inputs (A, B and C) determine which one of the outputs ($\bar{Y}0$ - $\bar{Y}7$) will go low.

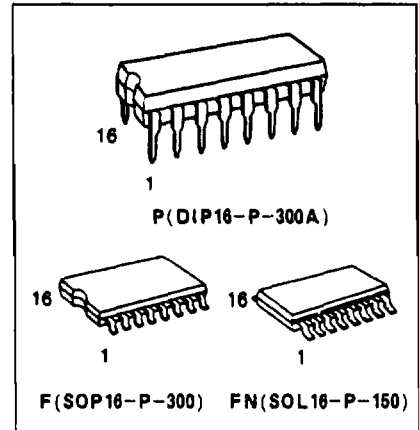
When enable input G1 is held low or either $\bar{G}2A$ or $\bar{G}2B$ is held high, decoding function is inhibited and all outputs go high.

G1, $\bar{G}2A$, and $\bar{G}2B$ inputs are provided to ease cascade connection and for use as an address decoder for memory systems.

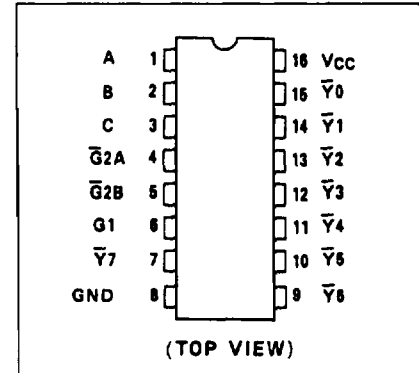
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

FEATURES:

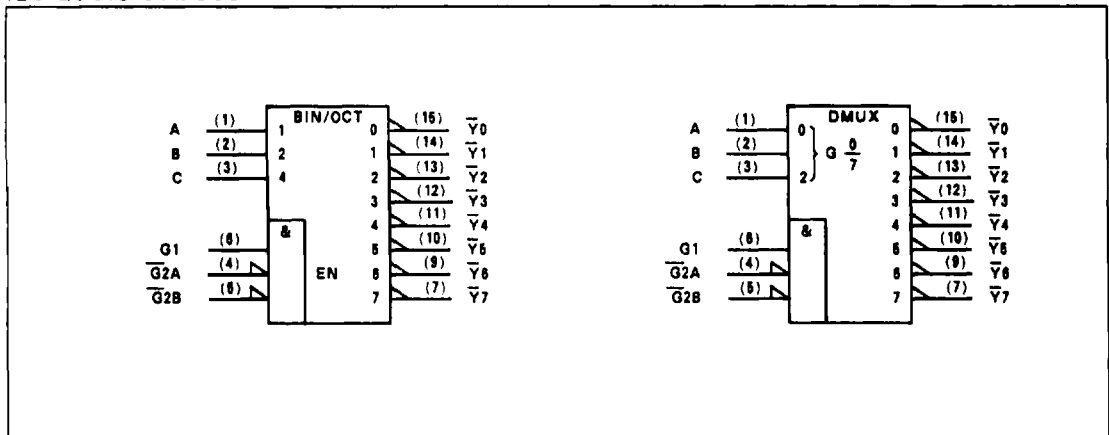
- High Speed $t_{pd}=5.9ns$ (typ.) at $V_{CC}=5V$
- Low Power Dissipation $I_{CC}=8\mu A$ (Max.) at $T_a=25^\circ C$
- High Noise Immunity $V_{NIH}=V_{NIL}=28\% V_{CC}$ (Min.)
- Symmetrical Output Impedance $|I_{OL}|=I_{OH}=24mA$ (Min.)
Capability of driving 50Ω transmission lines.
- Balanced Propagation Delays $t_{PLH} \approx t_{PHL}$
- Wide Operating Voltage Range $V_{CC(opr)}=2V \sim 5.5V$
- Pin and Function Compatible with 74F 138



PIN ASSIGNMENT



IEC LOGIC SYMBOL



ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	-0.5 ~ 6.0	V
DC Input Voltage	V_{IN}	-0.5 ~ $V_{CC} + 0.5$	V
DC Output Voltage	V_{OUT}	-0.5 ~ $V_{CC} + 0.5$	V
Input Diode Current	I_{IK}	±20	mA
Output Diode Current	I_{OK}	±50	mA
DC Output Current	I_{OUT}	±50	mA
DC V_{CC} /Ground Current	I_{CC}	±200	mA
Power Dissipation	P_D	500(DIP)* / 180(SOP)	mW
Storage Temperature	T_{stg}	-65 ~ 150	°C
Lead Temperature 10sec	T_L	300	°C

*500mW in the range of $T_a = -40^{\circ}\text{C} \sim 65^{\circ}\text{C}$. From $T_a = 65^{\circ}\text{C}$ to 85°C a derating factor of $-10\text{mW}/^{\circ}\text{C}$ shall be applied until 300mW.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	2.0~5.5	V
Input Voltage	V_{IN}	0 ~ V_{CC}	V
Output Voltage	V_{OUT}	0 ~ V_{CC}	V
Operating Temperature	T_{opr}	-40 ~ 85	°C
Input Rise and Fall Time	dt/dv	0~100($V_{CC} = 3.3 \pm 0.3\text{V}$)	ns/v
		0~ 20($V_{CC} = 5 \pm 0.5\text{V}$)	

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	V_{CC}	$T_a = 25^{\circ}\text{C}$			$T_a = -40 \sim 85^{\circ}\text{C}$		UNIT	
				MIN.	TYP.	MAX.	MIN.	MAX.		
High-Level Input Voltage	V_{IH}		2.0	1.50	-	-	1.50	-	V	
			3.0	2.10	-	-	2.10	-		
			5.5	3.85	-	-	3.85	-		
Low-Level Input Voltage	V_{IL}		2.0	-	-	0.50	-	0.50	V	
			3.0	-	-	0.90	-	0.90		
			5.5	-	-	1.65	-	1.65		
High-Level Output Voltage	V_{OH}	$V_{IN} =$	$I_{OH} = -50\mu\text{A}$	2.0	1.9	2.0	-	1.9	V	
				3.0	2.9	3.0	-	2.9		
		V_{IH} or V_{IL}	$I_{OH} = -4\text{mA}$	3.0	2.58	-	-	2.48		-
				4.5	3.94	-	-	3.80		-
Low-Level Output Voltage	V_{OL}	$V_{IN} =$	$I_{OL} = 50\mu\text{A}$	2.0	-	0.0	0.1	-	0.1	V
				3.0	-	0.0	0.1	-	0.1	
				4.5	-	0.0	0.1	-	0.1	
Input Leakage Current	I_{IN}	$V_{IN} = V_{CC}$ or GND	5.5	-	-	±0.1	-	±1.0	μA	
			3.0	-	-	±0.1	-	±1.0		
			5.5	-	-	±0.1	-	±1.0		
Quiescent Supply Current	I_{CC}	$V_{IN} = V_{CC}$ or GND	5.5	-	-	8.0	-	80.0	μA	

* This spec indicates the capability of driving 50Ω transmission lines.
One output should be tested at a time for a 10ms maximum duration.

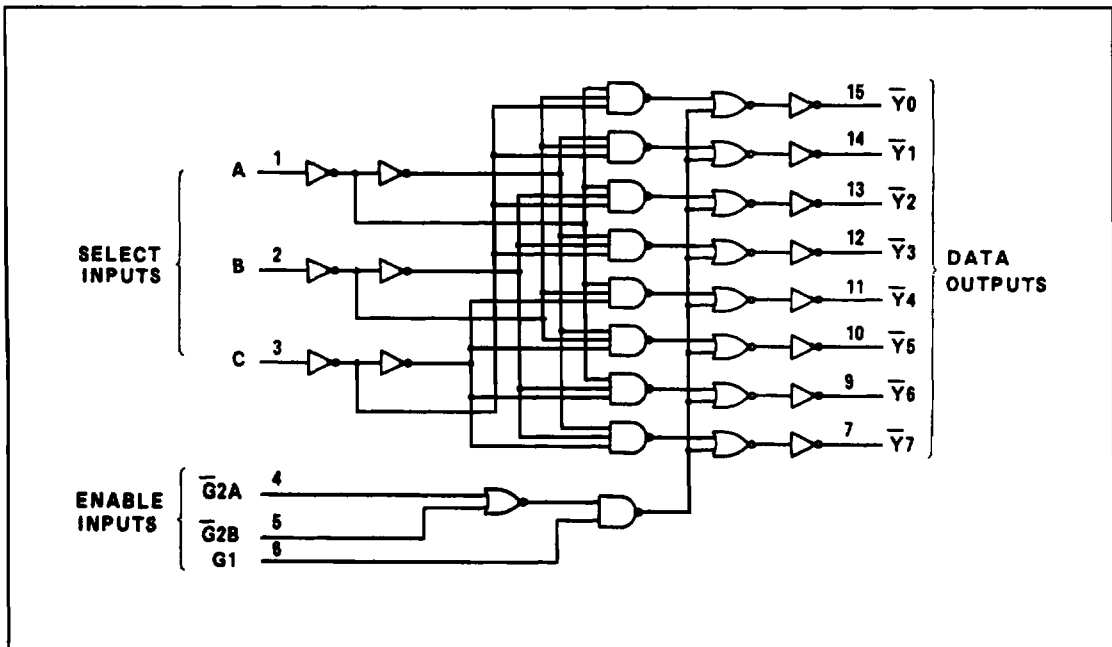
TC74AC138P/F/FN

TRUTH TABLE

INPUTS						OUTPUTS								SELECTED OUTPUT
ENABLE			SELECT			\bar{Y}_0	\bar{Y}_1	\bar{Y}_2	\bar{Y}_3	\bar{Y}_4	\bar{Y}_5	\bar{Y}_6	\bar{Y}_7	
G1	$\bar{G}2A$	$\bar{G}2B$	C	B	A									
L	X	X	X	X	X	H	H	H	H	H	H	H	H	NONE
X	H	X	X	X	X	H	H	H	H	H	H	H	H	NONE
X	X	H	X	X	X	H	H	H	H	H	H	H	H	NONE
H	L	L	L	L	L	L	H	H	H	H	H	H	H	\bar{Y}_0
H	L	L	L	L	H	H	L	H	H	H	H	H	H	\bar{Y}_1
H	L	L	L	H	L	H	H	L	H	H	H	H	H	\bar{Y}_2
H	L	L	L	H	H	H	H	H	L	H	H	H	H	\bar{Y}_3
H	L	L	H	L	L	H	H	H	H	L	H	H	H	\bar{Y}_4
H	L	L	H	L	H	H	H	H	H	H	L	H	H	\bar{Y}_5
H	L	L	H	H	L	H	H	H	H	H	H	L	H	\bar{Y}_6
H	L	L	H	H	H	H	H	H	H	H	H	H	L	\bar{Y}_7

X : DON'T CARE

LOGIC DIAGRAM



AC ELECTRICAL CHARACTERISTICS (C_L=50pF, R_L=500Ω, Input t_r=t_f=3ns)

PARAMETER	SYMBOL	TEST CONDITION	T _a =25°C				T _a =-40 ~85°C		UNIT
			V _{CC}	MIN.	TYP.	MAX.	MIN.	MAX.	
Propagation Delay Time (A, B, C- \bar{Y})	t _{pLH}		3.3±0.3	-	8.5	14.2	1.0	16.3	ns
	t _{pHL}		5.0±0.5	-	6.4	9.2	1.0	10.5	
Propagation Delay Time (G1- \bar{Y})	t _{pLH}		3.3±0.3	-	7.5	12.8	1.0	14.7	
	t _{pHL}		5.0±0.5	-	6.1	8.9	1.0	10.2	
Propagation Delay Time (G2- \bar{Y})	t _{pLH}		3.3±0.3	-	8.8	15.0	1.0	17.3	
	t _{pHL}		5.0±0.5	-	7.2	10.5	1.0	12.0	
Input Capacitance	C _{IN}		-	5	10	-	10	pF	
Power Dissipation Capacitance	C _{PD(1)}		-	143	-	-	-		

Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC(top)} = C_{PD} \cdot V_{CC} \cdot f_{IN} - I_{CC}$$